20V N-Channel Power MOSFET

UM2302S SOT23-3
UM2302P SOT323

General Description

The UM2302 is a low threshold N-channel MOSFET, have extremely low on-resistance. This benefit provides the designer with an extremely efficient device for use in battery and load management applications. The device uses a space-saving, small-outline SOT23-3 or SOT323 package.

Applications

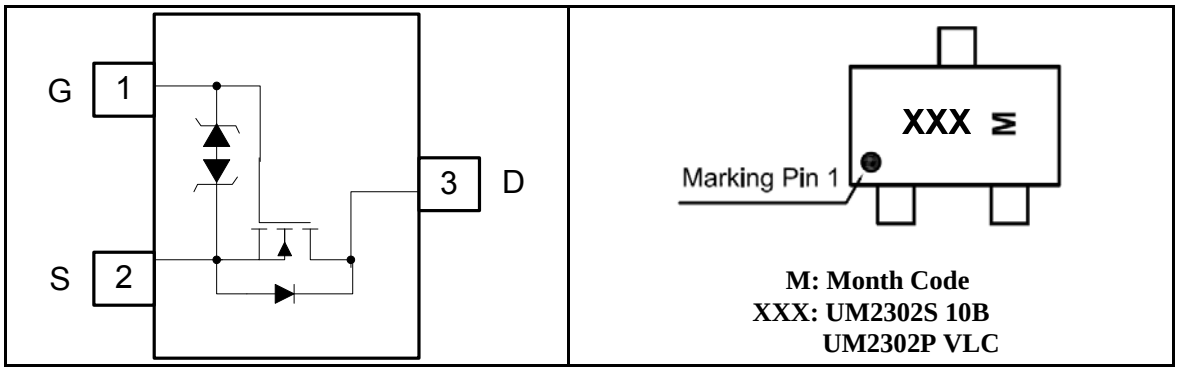
- Battery Packs
- Battery-powered Portable Equipment
- Cellular and Cordless Telephones

Features

- Drain-Source Voltage(max)：20V
- Low On-Resistance：
  90mΩ@V_{GS}=4.5V
  150mΩ@V_{GS}=2.5V
- Continuous Drain Current(max)：
  2A@25℃（SOT23-3）
  1.6A@25℃（SOT323）

Pin Configurations

Top View



M: Month Code
XXX: UM2302S 10B
UM2302P VLC

Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty
UM2302S	SOT23-3	10B	3000pcs/7 Inch Tape & Reel
UM2302P	SOT323	VLC	

Absolute Maximum Ratings

Symbol	Parameter		Value	Units
V_{DSS}	Drain-Source voltage		20	V
V_{GS}	Gate-Source voltage		±8	V
I_D	Continuous Drain Current (5s)	SOT23-3	2	A
		SOT323	1.6	
I_{DP}	Drain Current Pulsed (Pulse Width ≤ 10μs, Duty Cycle ≤ 1%)		5	A

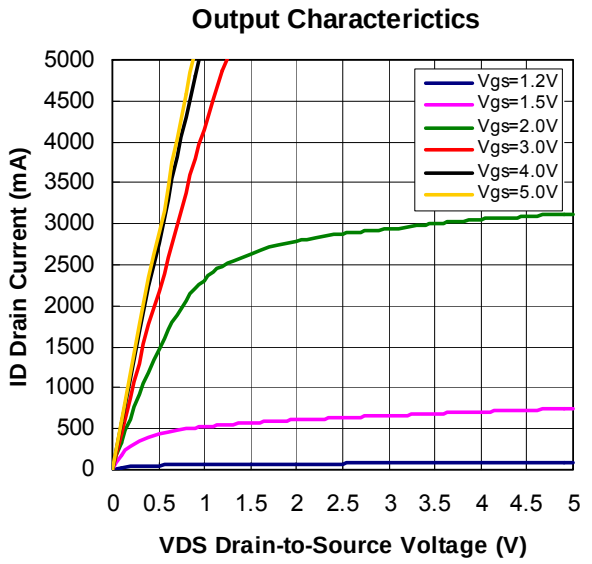
P_D	Power Dissipation	SOT23-3	0.86	W
		SOT323	0.5	
T_J	Junction Temperature		-55~150	℃
Tstg	Storage Temperature		-55~150	℃
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (≤5s)	SOT23-3	145	℃/W
		SOT323	250	
ESD	ESD Method 3015.8		2000	V

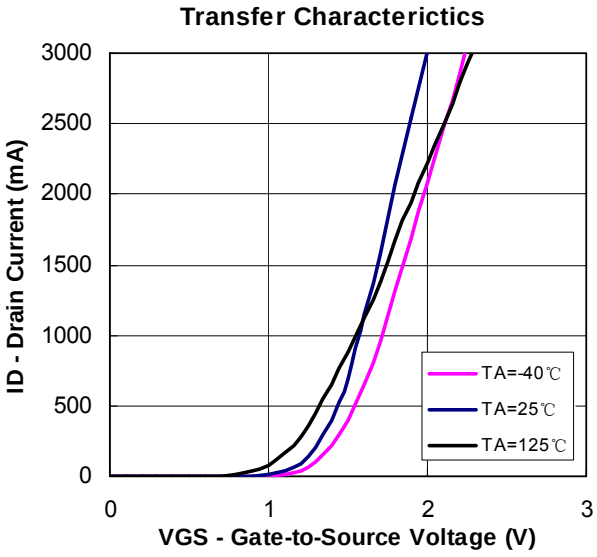
Electrical Characteristics (T_J=25℃, Unless otherwise noted)

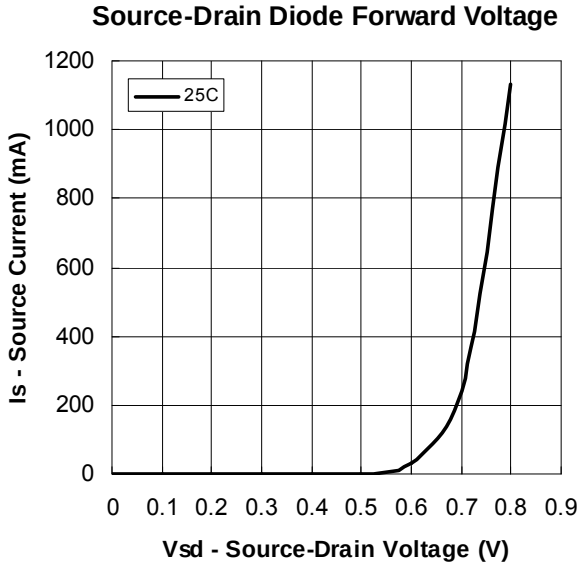
Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
Off Characteristics						
BV_{DSS}	Drain to Source Breakdown Voltage	V_{GS}=0V, I_D=250μA	20			V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS}=20V, V_{GS}=0V			0.1	μA
I_{GSS}	Gate-to-Source Leakage Current	V_{GS}=±8V, V_{DS}=0V			±10	μA
On Characteristics						
$R_{DS(ON)}$	Static Drain-to-Source On-Resistance [a]	V_{GS}=4.5V, I_D=1.0A		90	150	mΩ
		V_{GS}=2.5V, I_D=1.0A		150	200	
$V_{GS(TH)}$	Gate-Source Threshold Voltage	V_{DS}= V_{GS} , I_D=250μA	0.40		0.90	V
g_{fs}	Forward Transconductance [a]	V_{DS}=5V, I_D=2A		4.5		S
Dynamic Characteristics [b]						
Ciss	Input Capacitance	V_{GS}=0V, V_{DS}=10V, f=1.0MHz		150		pF
Coss	Output Capacitance			50		
Crss	Reverse Transfer Capacitance			40		
Switching Characteristics [b]						
td(on)	Turn-on Delay Time	V_{DD}=10V, R_L=2.78Ω, I_D=3.6A, V_{GEN}=4.5V, R_G=1Ω		8	15	ns
tr	Rise Time			10	25	
td(off)	Turn-off Delay Time			30	45	
tf	Fall Time			25	40	
Drain-Source Diode Characteristics and Maximum Ratings						
V_{SD}	Forward Diode Voltage	I_S=0.95A, V_{GS}=0V		0.7	1.2	V

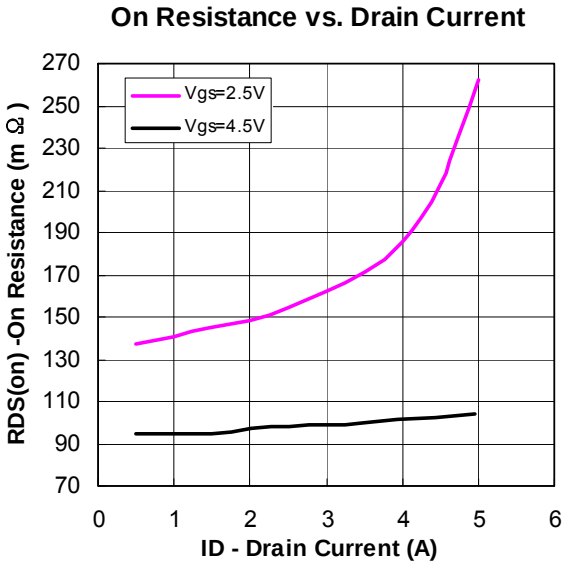
a: Pulse test: pulse width ≤ 300μs, duty cycle ≤ 2%.
b: Guaranteed by design, not subject to production testing.

Typical Characteristics (T_J=25℃, Unless otherwise noted)



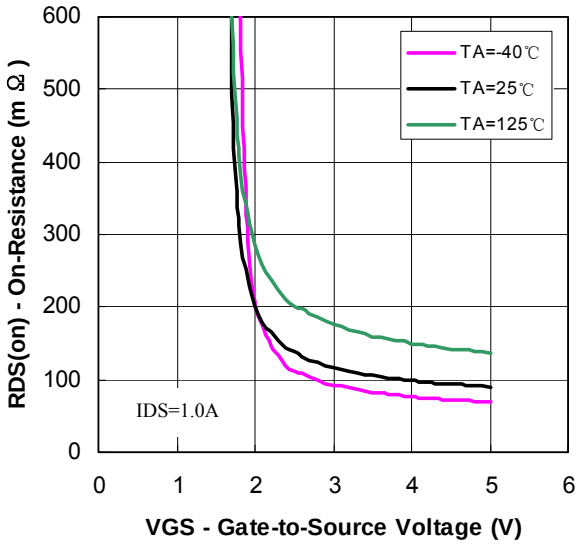




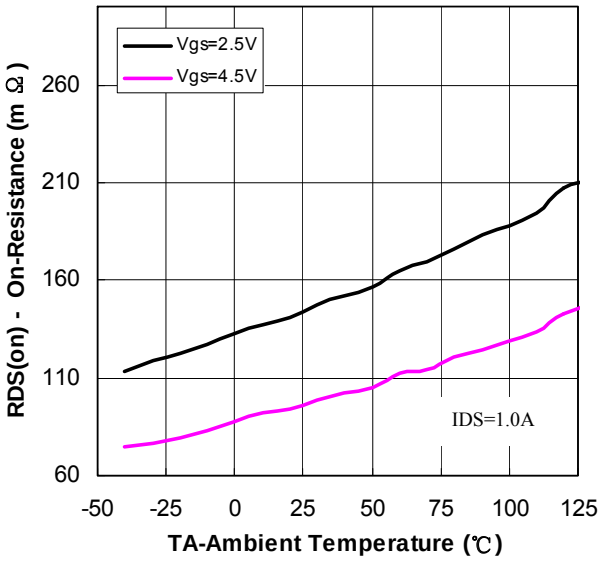


Typical Characteristics (T_J=25℃, Unless otherwise noted)

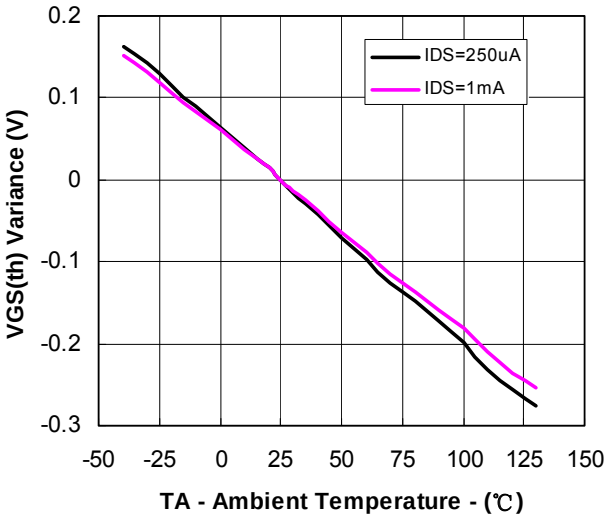
On-Resistance vs. Gate-to-Source Voltage



On-Resistance vs. Ambient Temperature



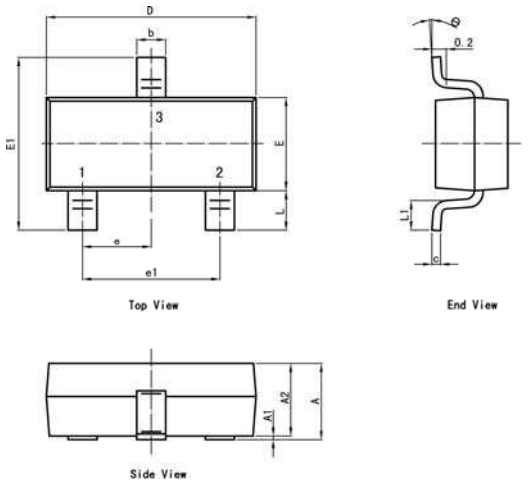
Threshold Voltage vs. Ambient Temperature



Package Information

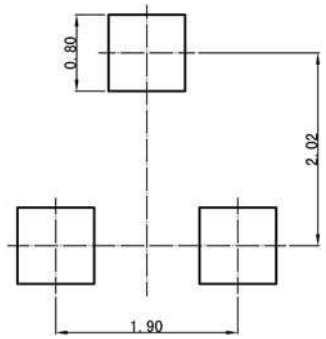
UM2302S SOT23-3

Outline Drawing



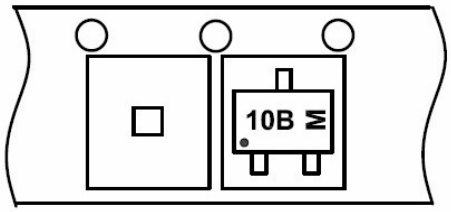
Symbol	DIMENSIONS			
	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950REF		0.037REF	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

Land Pattern



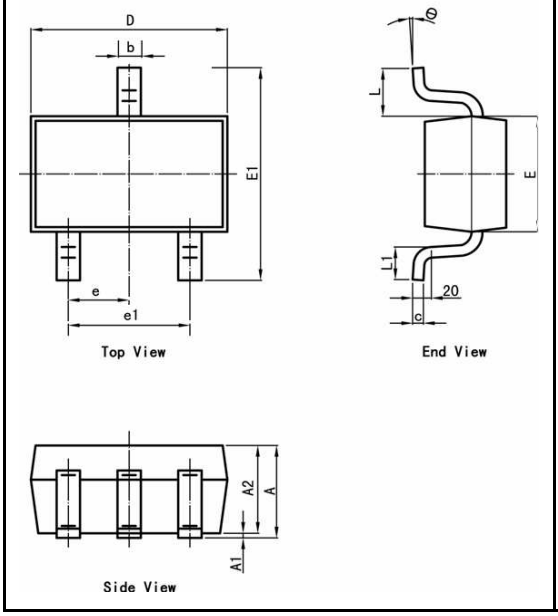
NOTES:
1. Compound dimension: 2.92×1.60;
2. Unit: mm;
3. General tolerance ±0.05mm unless otherwise specified;
4. The layout is just for reference.

Tape and Reel Orientation



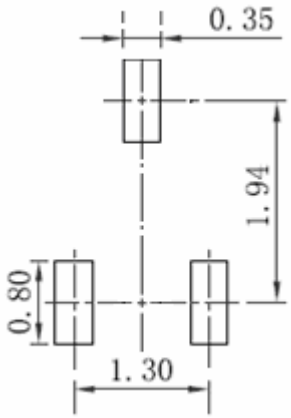
UM2302P SOT323

Outline Drawing



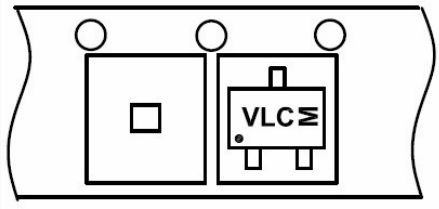
Symbol	DIMENSIONS			
	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.877	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.220	0.003	0.009
D	1.800	2.200	0.071	0.087
E	1.150	1.350	0.045	0.053
E1	2.000	2.450	0.079	0.096
e	0.650REF		0.026REF	
e1	1.200	1.400	0.047	0.055
L	0.488REF		0.020REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

Land Pattern



NOTES:
1. Compound dimension: 2.10×1.25;
2. Unit: mm;
3.General tolerance ±0.05mm unless otherwise specified;
4. The layout is just for reference.

Tape and Reel Orientation



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Union Semiconductor, Inc
Add: 2F, No. 3, Lane 647 Songtao Road, Shanghai 201203
Tel: 021-51093966
Fax: 021-51026018
Website: www.union-ic.com